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## Supplementary information

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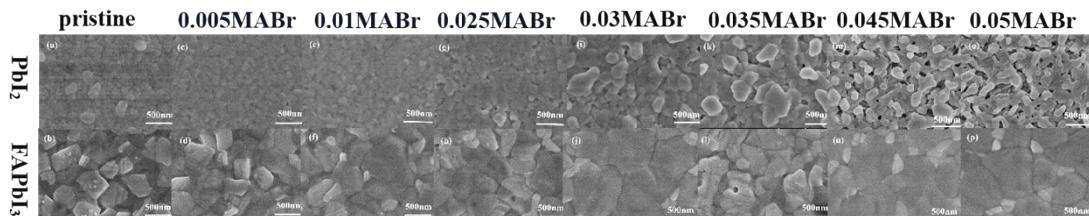
# Inhibition PbI<sub>2</sub>-induced defects by doping MABr for high-performance perovskite solar cells

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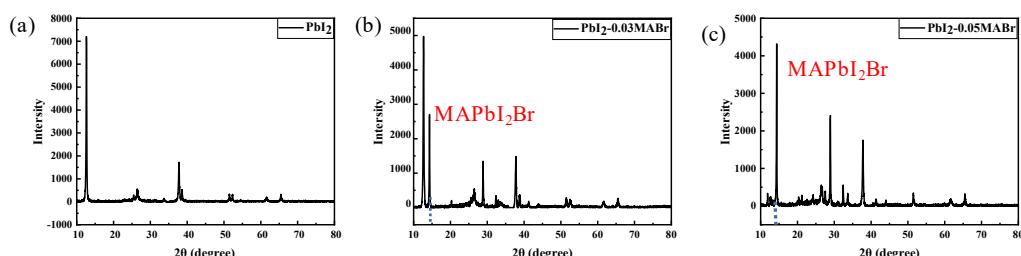
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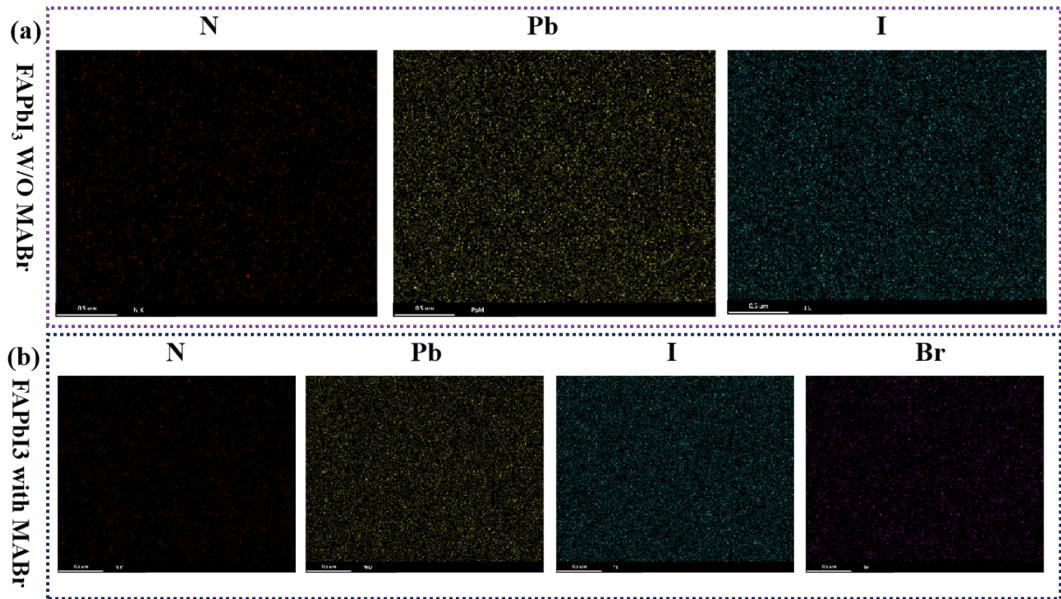
\*Email of corresponding author: q397983012@126.com



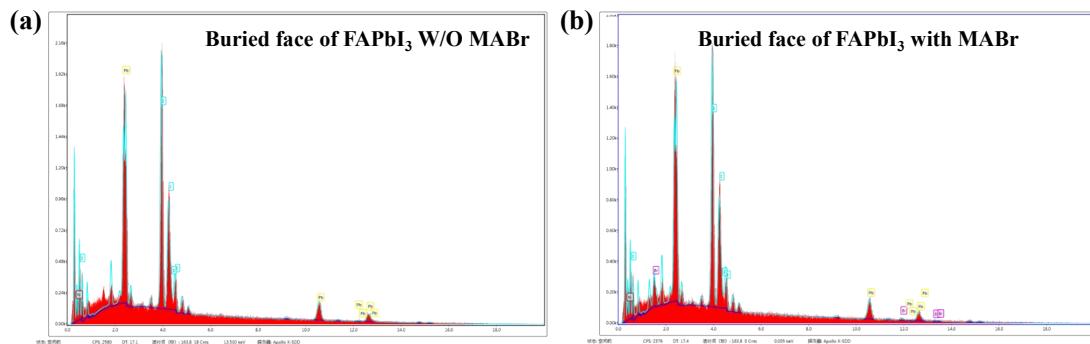
Supplementary Fig. 1. (a), (c), (e), (g), (i), (k), (m), (o) shows the SEM images of PbI<sub>2</sub> with MABr = 0, 0.005, 0.01, 0.025, 0.03, 0.035, 0.045, 0.05; whereas Fig. 1 (b), (d), (f), (h), (j), (l), (n), (p) shows the SEM images of corresponding FAPbI<sub>3</sub>.



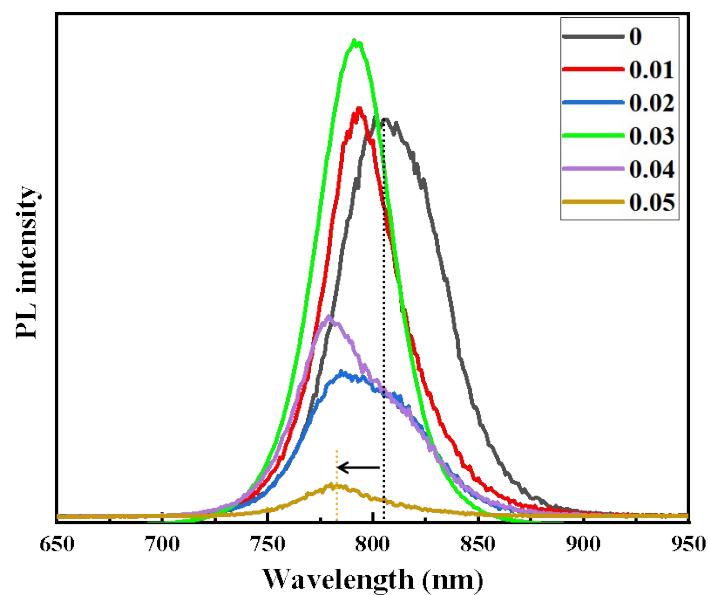
Supplementary Fig. 2. XRD patterns of (a) PbI<sub>2</sub>; (b) PbI<sub>2</sub>-0.03MABr; (c) PbI<sub>2</sub>-0.05MABr.



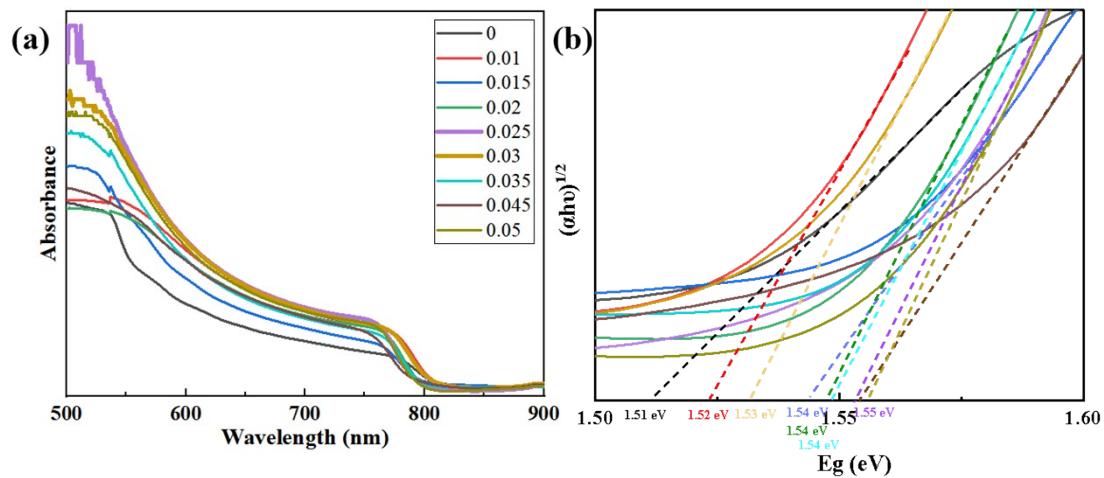
Supplementary Fig. 3. The elements distribution diagram of the FAPbI<sub>3</sub> buried face without MABr (a) and with MABr (b).



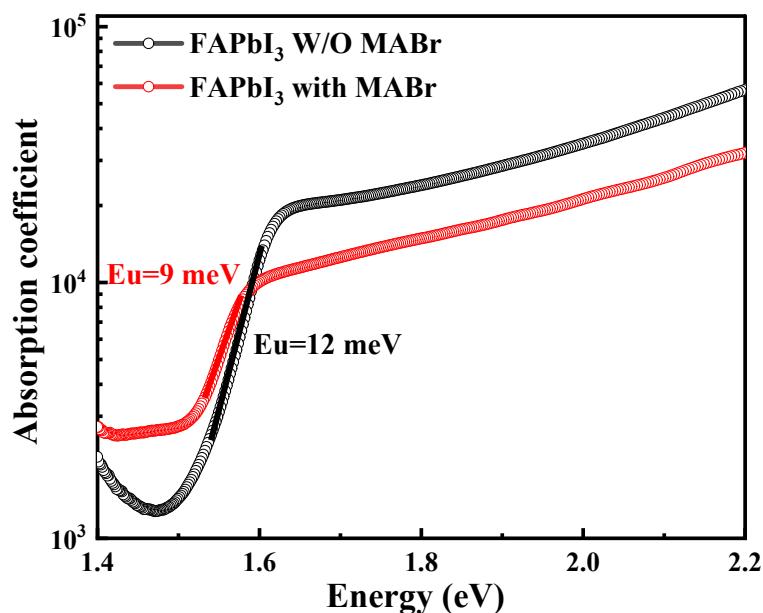
Supplementary Fig. 4. The full elements distribution spectrum of the buried face of FAPbI<sub>3</sub> (a) without and (b) with MABr.



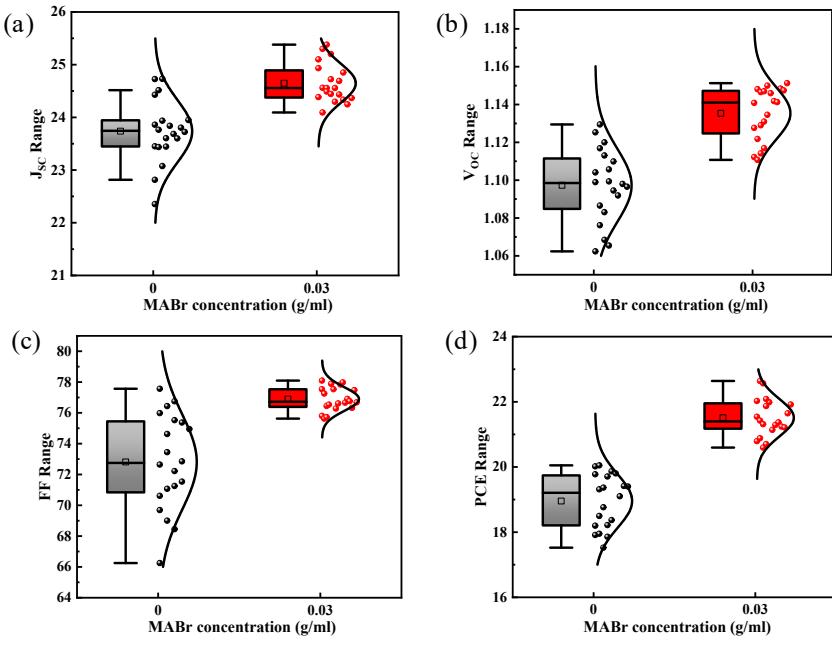
Supplementary Fig. 5. PL spectrum for FAPbI<sub>3</sub> samples with MABr from 0 to 0.05 g/ml.



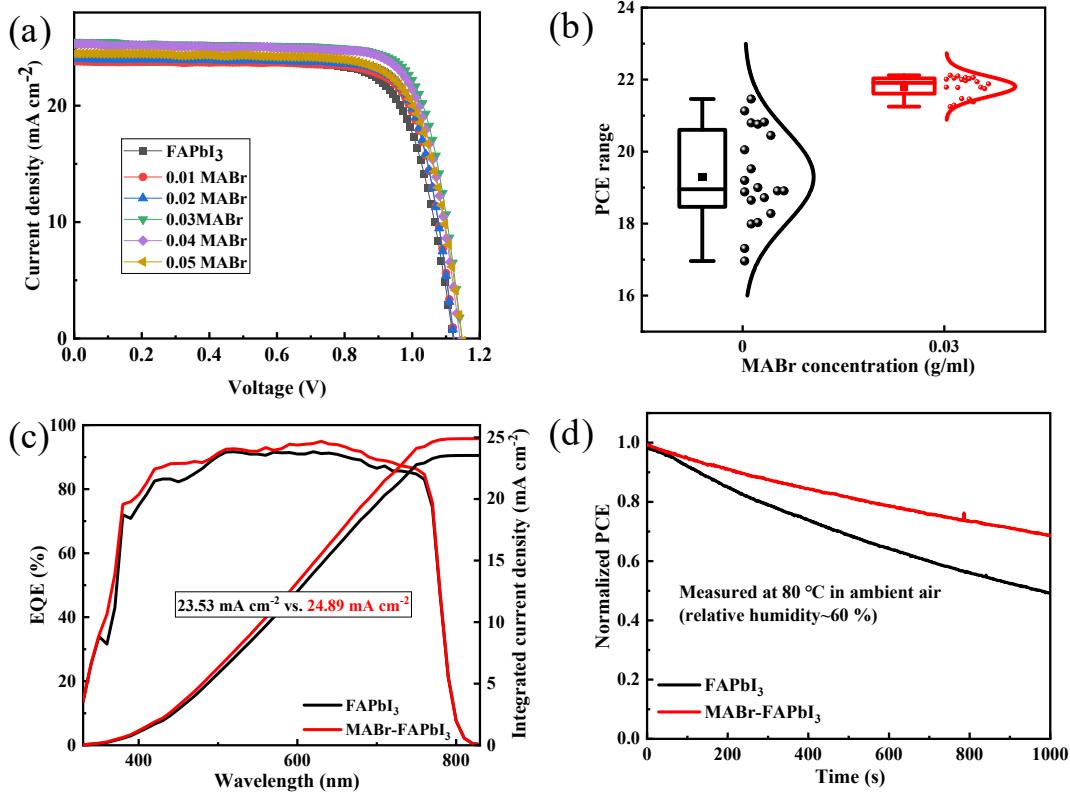
Supplementary Fig. 6. (a) Absorption spectra of as-prepared films with increasing MABr from 0 to 0.05g/ml; (b) the band gaps of these corresponding films.



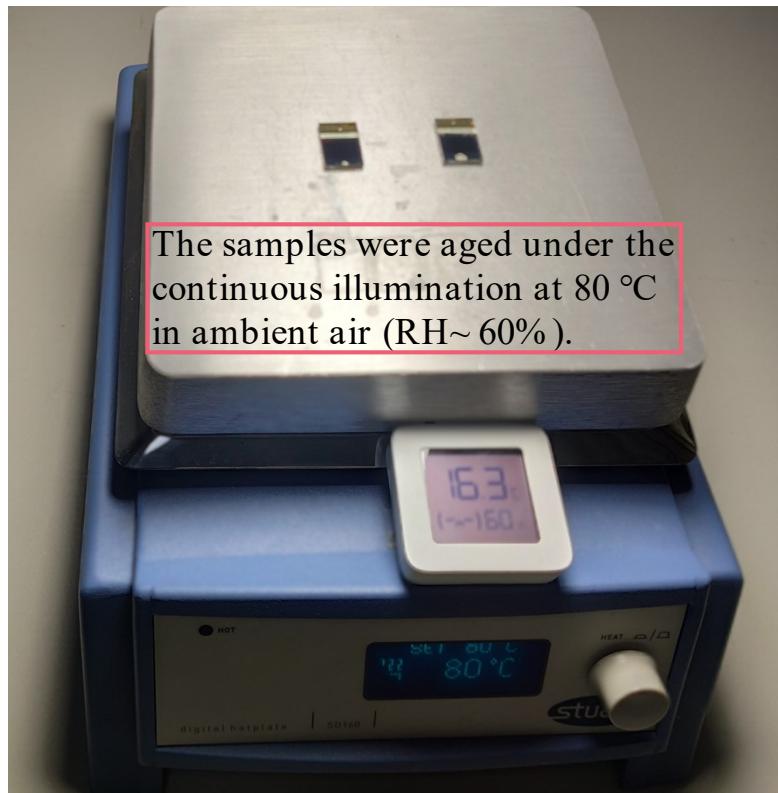
Supplementary Fig. 7. The Urbach tail energy from the Tauc plot of FAPbI<sub>3</sub> without (Black line) and with (Red line) MABr.



Supplementary Fig. 8. Statistical plot of FAPbI<sub>3</sub> with MABr = 0, 0.03 g/ml: (a)  $J_{sc}$ ; (b)  $V_{oc}$ ; (c) FF; (d) PCE.



Supplementary Fig. 9. (a) Current-Voltage curves of FAPbI<sub>3</sub> under different doping concentration of MABr = 0, 0.01, 0.02, 0.03, 0.04, 0.05 g/ml; (b) statistical plot of FAPbI<sub>3</sub> with MABr = 0, 0.03 g/ml; (c) IPCE spectra obtained for the devices with and without MABr; (d) the device performance test at 80 °C in ambient air (relative humidity of 60) for 1000 seconds.



Supplementary Fig. 10. Stability test at 80 °C in ambient air (relatively humidity of 60 %) for 1000 seconds

Table S1 Performance parameters of PSCs with various MABr concentration.

MABr concentration	$J_{SC}$ ( $\text{mA cm}^{-2}$ )	$V_{OC}$ (V)	FF (%)	PCE (%)
0	23.95	1.12	74.95	20.05
0.01	23.76	1.12	77.11	20.51
0.02	23.98	1.12	78.58	21.11
0.03	25.30	1.15	77.84	22.64
0.04	25.14	1.14	77.38	22.23
0.05	24.45	1.15	75.01	21.08

Table S2. Fitted EIS parameters for the PSCs based on pristine  $\text{FAPbI}_3$  and MABr modified  $\text{FAPbI}_3$  ETLs.

ETL	$R_s$	$R_{tr}$	$C_{tr}$	$R_{rec}$	$C_{rec}$
$\text{FAPbI}_3$	9.8	58.28	$1.3 \times 10^{-7}$	49.4	$1.1 \times 10^{-7}$
MABr- $\text{FAPbI}_3$	7.1	9.8	$1.1 \times 10^{-6}$	58.3	$2.4 \times 10^{-7}$

